PATENT S/N 09/489954

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Examiner: Donghee Kang Pierre C. Fazan et al. Applicant:

Serial No.:

09/489954

Group Art Unit: 2811

Filed:

January 24, 2000

Docket: 303.434US2

Title:

METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE

WITH HIGH DIELECTRIC CONSTANT MATERIALS

COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

<u>Serial/Patent No.</u> 08/044331	Filing Date April 2, 1993	Attorney Docket 303.433US1	Title METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS
08/390336 5478772	February 17, 1995	303.433US2	METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS
08/572392 6030847	December 14, 1995	303.434US1	METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS
08/104524 5392189	August 10, 1993	303.445US1	CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS HAVING TWO INDEPENDENT INSULATIVE LAYERS AND THE METHOD FOR FORMING SAME

COMMUNICATION CONCERNING RELATED APPLICATIONS

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Title: METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS CAPACITOR COMPATIBLE WITH 08/314117 September 303.445US2 6066528 27, 1994 HIGH DIELECTRIC CONSTANT MATERIALS HAVING TWO INDEPENDENT INSULATIVE LAYERS AND THE METHOD FOR FORMING SAME 09/357634 July 20, 303.445US3 METHOD FOR FORMING A 1999 CAPACITOR COMPATIBLE WITH 6495427 HIGH DIELECTRIC CONSTANT MATERIALS HAVING TWO INDEPENDENT INSULATIVE LAYERS CAPACITOR COMPATIBLE WITH 08/104525 303.446US1 August 10, HIGH DIELECTRIC CONSTANT 5381302 1993 MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME 08/313677 September 303.446US2 CAPACITOR COMPATIBLE WITH 5506166 27, 1994 HIGH DIELECTRIC CONSTANT MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME CAPACITOR COMPATIBLE WITH 08/572846 December 303.446US3 5959327 14, 1995 HIGH DIELECTRIC CONSTANT MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME CAPACITOR COMPATIBLE WITH 09/362326 July 27, 303.446US4 1999 HIGH DIELECTRIC CONSTANT 6531730 MATERIALS HAVING A LOW CONTACT RESISTANCE LAYER AND THE METHOD FOR FORMING SAME

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Serial Number: 09/489954

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Title: METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS

Respectfully submitted,

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I hereby certify that this paper is being transmitted by facsimile to the U.S. Patent and Trademark Office on the date shown below.

Amy J. Moriarry

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